

SI-8011NVS**Surface-Mount, Synchronous Rectifier Step-down Switching Mode Regulator Control ICs****■Features**

- Surface-mount package (TSSOP24)
- High efficiency due to synchronous rectification: 93% (at $V_{IN} = 5V$, $I_O = 1A$, $V_O = 2.5V$)
- Capable of downsize a choke-coil due to IC's high switching frequency (125kHz typ, On Time Control). (Compared with conventional Sanken devices)
- Low reference voltage (V_{ref}) of 1.1V. The output voltage is variable from 1.1V to 6V.
- High-speed response to a load
- Compatible with low ESR capacitors
- Soft start and output ON/OFF available
- Built-in overcurrent protection circuit
- PWRGD function to indicate the output voltage status
- High precision reference voltage: $1.1V \pm 1.2\%$

■Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Control-System DC Input Voltage	V_{CC}	7	V
DC Input Voltage	V_{IN}	25	V
Boost Block Input Voltage	V_H	30	V
EN Terminal Input Voltage	V_{EN}	V_{CC}	V
PWRGD Terminal Applied Voltage	V_{PWRGD}	7	V
Junction Temperature	T_J	+150	°C
Storage Temperature	T_{STG}	-40 to +150	°C

■Applications

- Power supplies for notebook PCs and mobile devices
- Onboard local power supplies
- OA equipment
- For stabilization of the secondary-side output voltage of switching power supplies

■Recommended Operating Conditions

Parameter	Symbol	Ratings	Unit
Control System Input Voltage Range	V_{CC}	4.5 to 5.5	V
Input Voltage Range	V_{IN}	3 to 18	V
Output Voltage Range	V_O	1.1 to 6	V
Operating Temperature Range	T_{OP}	-20 to +85	°C

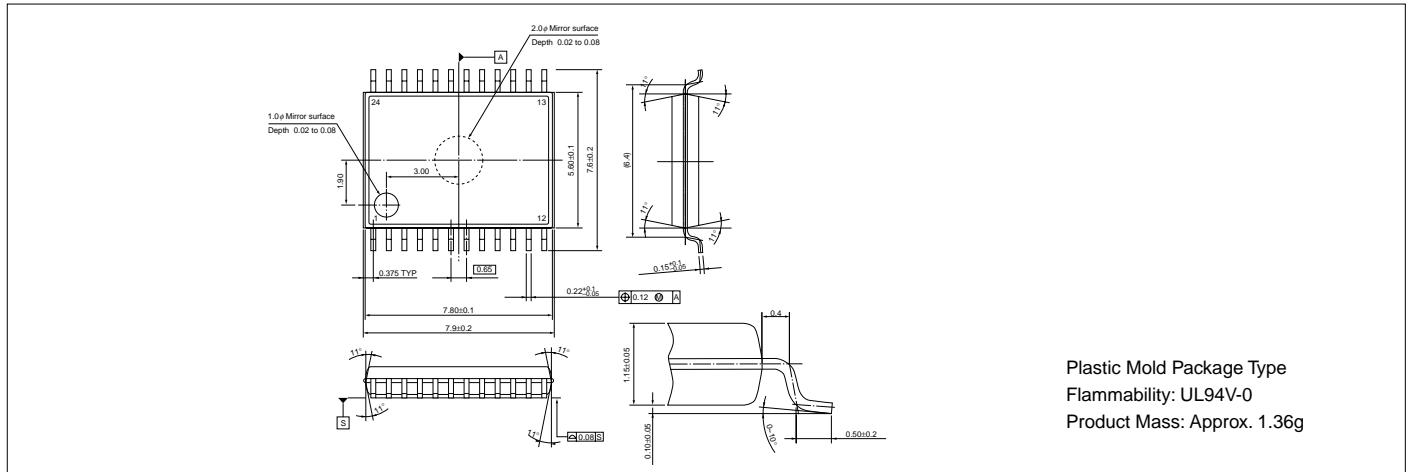
■Electrical Characteristics

(Ta = 25°C unless otherwise specified)

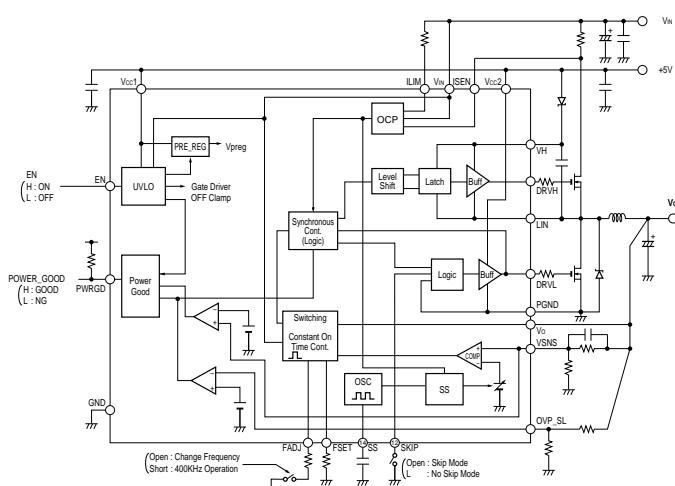
Parameter	Symbol	Ratings			Unit	Conditions
		min.	typ.	max.		
Dynamic Characteristics	Output Voltage	V_O	-1.2%	1.1	+1.2%	V
	Temperature Coefficient of Output Voltage	$\Delta V_O / \Delta T$		±0.03		mV/°C
Circuit Current	Circuit Current (Vcc Terminal)	I_{OP}		6	mA	Vcc=5V, EN=H, FADJ:open
	Circuit Current (Vin Terminal)	I_{OP}		1	mA	Vin=5V, EN=H
Undervoltage Lockout	Standby Current 1 (Vcc Terminal)	I_{STD1}		100	μA	Vcc=5V, EN=L
	Standby Current 2 (Vin Terminal)	I_{STD2}		50	μA	Vin=5V, EN=L
On Time Control	UVLO Operating Voltage 1 (Vcc Terminal)	V_{UVLO1}	3.7		4.4	V
	UVLO Operating Voltage 2 (Vin Terminal)	V_{UVLO2}	2.5		2.9	V
High Side Drive	On Time	T_{ON}		2	μS	Vcc=5V, Vin=5V, Vo=2.5V
	Minimum Off Time	T_{OFF}		1	μS	Vcc=5V
Low Side Drive	REF Terminal Voltage	V_{REF}	1.1	1.2	1.3	V
	REF Terminal Source Current	I_{REF}		100	μA	Vcc=5V
Bootstrap	On Resistance (high side)	R_{ONHH}		5.5	Ω	VH-VLIN=5V
	On Resistance (low side)	R_{ONHL}		5.5	Ω	VH-VLIN=5V
Protection System	On Resistance (high side)	R_{ONLH}		5.5	Ω	Vcc=5V
	On Resistance (low side)	R_{ONLL}		5.5	Ω	Vcc=5V
Protection System	Bootstrap Voltage	V_{H-VLIN}	4.5	5	5.5	V
	Current for Current Limit Detection	I_{ILIM}	90	100	110	μA
	Soft Start Terminal Current	I_{SS}		±20		μA
	EN Low Level Voltage	V_{CELO}	0		0.8	V
	EN High Level Voltage	V_{CEHI}	2.4		Vcc	V
	EN Bias Level Current	I_{ICE}			5	μA
	PWRGD Good Voltage (high side)	V_{SENS}		1.32		V
	PWRGD Good Voltage (low side)	V_{SENS}		0.88		V
	PWRGD Low Output Voltage	V_{PWRGD}			0.4	V
	PWRGD Terminal Current	I_{PWRGD}			120	μA
	PWRGD Leakage Current	I_{PWRGD}			5	μA

■External Dimensions (TSSOP24)

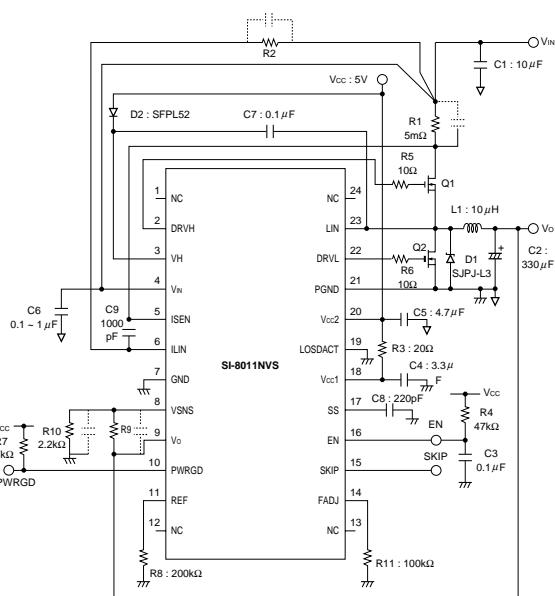
(Unit : mm)



■Block Diagram (Pin Assignment)



■Typical Connection Diagram



MOS FET Q₁, Q₂

- Be sure to use logic type MOS FET as Q₁ and Q₂. If you use a normal power MOS FET type, the ON resistance may not drop to a satisfactory level due to a shortage of V_{gs}. This may deteriorate the efficiency and cause overheating.

Diode D₁

- Be sure to use a Schottky-barrier diode for D₁. If other diodes like fast recovery diodes are used, IC may be destroyed because of the reverse voltage generated by the recovery voltage or ON voltage.

Choke coil L₁

- If the winding resistance of the choke coil is too high, the efficiency may drop below the rated value.
- Take care concerning heat radiation from the choke coil caused by magnetic saturation due to overload or short-circuit load.

Capacitor C₁, C₂

- As large ripple currents flow through C₁ and C₂, use high-frequency and low-impedance capacitors aiming for switching-mode-power-supply use. Especially when the impedance of C₂ is high, the switching waveform may become abnormal at low temperatures. For C₂, do not use a capacitor with an extremely low equivalent series resistance (ESR) such as a ceramic capacitor, which may cause an abnormal oscillation.

* To create the optimum operating conditions, place the components as close as possible to each other.